# **REASUNOS**

# **MBR20150CT MBRF20150CT**

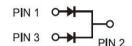
## SCHOTTKY BARRIER RECTIFIER





TO-220AB/MBR

ITO-220 /MBRF



# Po Lead Free Package and Finish

#### **FEATURES**

- Low forward voltage
- · High current capability
- · High forward surge capability
- Low power losses, High efficiency
- · Guarding for over voltage protection

### **APPLICATIONS**

Low VF Schottky barrier rectifier are designed for high frequency, miniature switched mode power supplies such as adapters ,lighting and on-board DC/DC conerters

Primary Characteristic				
Io	2*10A			
$V_{RRM}$	150V			
I <sub>FSM</sub>	290A			
$V_{F}$	0.72V			
T₃max	150℃			

#### **MECHANICAL DATA**

Case: Molded plasticPolarity: As markedMounting Position: Any

Molded Plastic: UL Flammability Classification Rating 94V-0
Lead free in compliance with EU RoHS 2011/65/EU directive

• Solder bath temperature 275℃ maximum,10s per JESD 22-B106

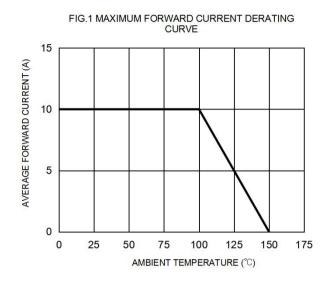
Maximum Ratings (Per Leg) at Ta=25°C	unless ot	herwise specified		
Characteristics	Symbol	Value	Unit	
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	150	V	
Working Peak Reverse Voltage	$V_{RWM}$	150	V	
Maximum DC Blocking Voltage	$V_{DC}$	150	V	
Mayirayan Ayarana Faryand Bastified Cymrat		10	Α	
Maximum Average Forward Rectified Current Total	I <sub>O</sub>	20		
Peak Forward Surge Current,8.3 ms Single Half Sine-wave	I <sub>FSM</sub>	290	Α	
Operating Temperature Range	$T_J$	150	°C	
Storage Temperature Range	$T_{STG}$	-40 to +150	°C	
Typical Thermal Resistance (Note1)				
TO-220AB	R <sub> <math>\theta</math> JC</sub>	2	°C/W	
ITO-220	-	4		

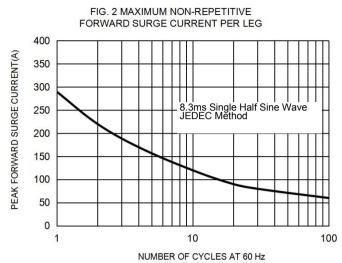
 $\label{thm:local_problem} \textbf{Note1: Thermal resistance from Junction to case per leg mounted on heatsink.}$ 

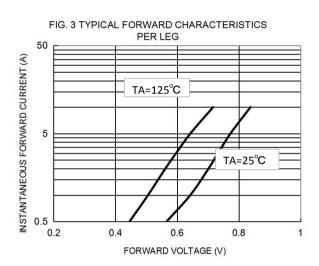
Electrical Characteristics (P	er Leg) unle	ss otherwis	e specified		
Characteristics		Symbol	Value		Unit
Forward Voltage Drop(Note2)			Тур.	Max.	
at I <sub>F</sub> =3A	TA=25°C		0.73	-	
	TA=125°C		0.60	-	
at I <sub>F</sub> =5A	TA=25°C	V <sub>F</sub>	0.77	-	V
	TA=125°C		0.64	-	
at I <sub>F</sub> =10A	TA=25°C		0.84	0.90	
	TA=125°C	1	0.72	-	
Maximum Reverse Current at V <sub>R</sub> =150V	TA=25°C		1	10	μA
	TA=125°C	I <sub>R</sub>	1	-	mA

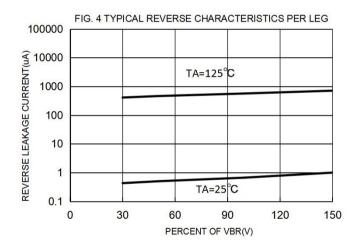
Note2:Pulse test: 300 µs pulse width, 1 % duty cycle

## RATINGS AND CHARACTERISTIC CURVES



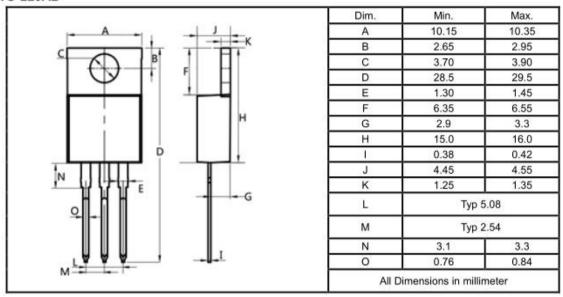




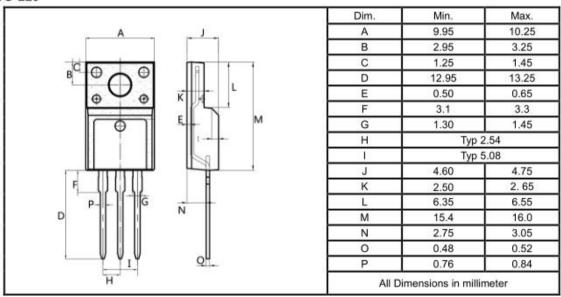


## Package Outline Dimensions millimeters

#### TO-220AB



#### TO-220



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